

# LLC Current-Resonant Off-Line Switching Controller SSC3S931

## Data Sheet

### Description

The SSC3S931 is a controller with SMZ\* method for LLC current resonant switching power supplies, incorporating a floating drive circuit for a high-side power MOSFET. The product includes useful functions such as the automatic dead time adjustment and the capacitive mode detection.

The product achieves high efficiency, low noise, and high cost-effective power supply systems with few external components.

\*SMZ is the soft-switched multi-resonant zero current switch, and is achieved soft switching operation during all switching periods.

### Package

SOP18



Not to scale

### Features

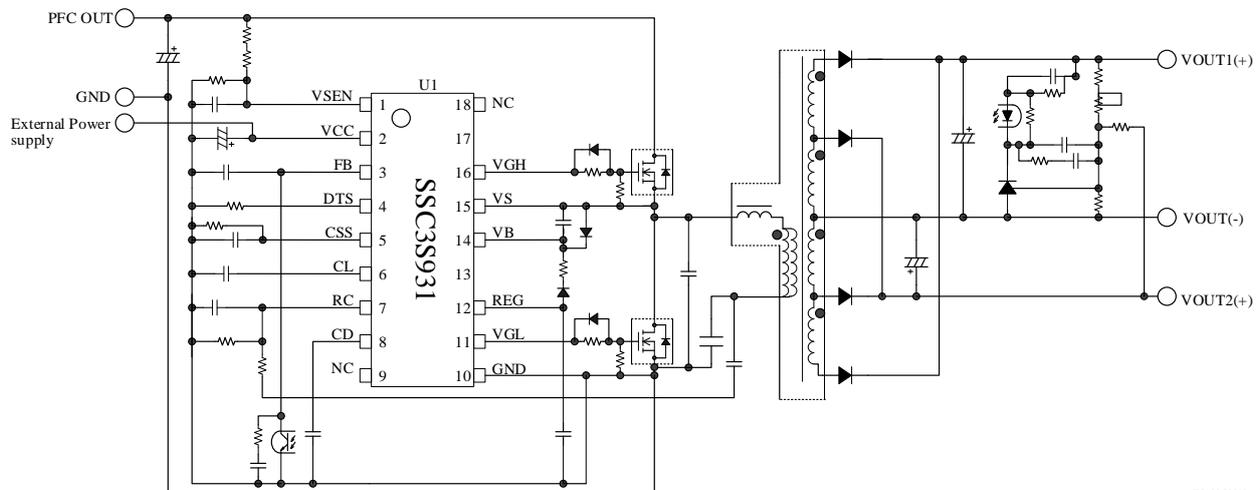
- Soft Start Function
- Capacitive Mode Detection Function
- Reset Detection Function
- Automatic Dead Time Adjustment Function
- Protections
  - High-side Driver UVLO: Auto-restart
  - VCC Pin Output Overvoltage Protection (VCC\_OVP): Latched Shutdown
  - Input Overvoltage Protection (HVP): Latched Shutdown
  - Input Undervoltage Protection (UVP): Auto-restart
  - Overcurrent Protection (OCP): Auto-restart, peak drain current detection, 2-step detection
  - Overload Protection (OLP): Latched Shutdown
  - Optocoupler Open Protection (OOP): Latched Shutdown
  - Thermal Shutdown (TSD) : Latched Shutdown

### Applications

Switching power supplies for electronic devices such as:

- Audio Visual (AV) Equipment
- Office Automation (OA) Equipment
- Industrial Apparatus
- Communication Facilities

### Typical Application



TC\_SSC3S931\_1\_R1

## Contents

Description .....	1
Contents .....	2
1. Absolute Maximum Ratings .....	3
2. Electrical Characteristics .....	4
3. Block Diagram .....	6
4. Pin Configuration Definitions .....	7
5. Typical Application .....	7
6. Physical Dimensions .....	8
7. Marking Diagram .....	8
8. Operational Description .....	9
8.1 Resonant Circuit Operation .....	9
8.2 Startup Operation .....	12
8.3 Soft Start Function .....	12
8.4 Minimum and Maximum Switching Frequency Setting .....	13
8.5 High-side Driver .....	13
8.6 Constant Voltage Control Operation .....	13
8.7 Dead Time Adjustment Function .....	14
8.8 Capacitive Mode Detection Function .....	14
8.9 Reset Detection Function .....	16
8.10 VCC Pin Overvoltage Protection (VCC_OVP) .....	17
8.11 Input Overvoltage Protection (HVP), Input Undervoltage Protection (UVP) .....	17
8.12 Overcurrent Protection (OCP) .....	17
8.12.1 Overcurrent Protection 1 (OCP1) .....	18
8.12.2 Overcurrent Protection 2 (OCP2) .....	18
8.13 Overload Protection (OLP) .....	18
8.14 Optocoupler Open Protection (OOP) .....	18
8.15 Thermal Shutdown (TSD) .....	19
9. Design Notes .....	19
9.1 External Components .....	19
9.1.1 Input and Output Electrolytic Capacitors .....	19
9.1.2 Resonant Transformer .....	19
9.1.3 Current Detection Resistor, $R_{OCP}$ .....	19
9.1.4 Current Resonant Capacitor, $C_i$ .....	19
9.1.5 Gate Pin Peripheral Circuit .....	19
9.2 PCB Trace Layout and Component Placement .....	20
10. Pattern Layout Example .....	22
Important Notes .....	23

## 1. Absolute Maximum Ratings

Current polarities are defined as follows: current going into the IC (sinking) is positive current (+); and current coming out of the IC (sourcing) is negative current (-).

Unless otherwise specified,  $T_A$  is 25°C.

Characteristic	Symbol	Pins	Rating	Unit
VSEN Pin Sink Current	$I_{SEN}$	1 – 10	1.0	mA
Control Part Input Voltage	$V_{CC}$	2 – 10	-0.3 to 35	V
FB Pin Voltage	$V_{FB}$	3 – 10	-0.3 to 6	V
DTS Pin Voltage	$V_{DTS}$	4 – 10	-0.3 to $V_{REG}$	V
CSS Pin Voltage	$V_{CSS}$	5 – 10	-0.3 to 6	V
CL Pin Voltage	$V_{CL}$	6 – 10	-0.3 to 6	V
RC Pin Voltage	$V_{RC}$	7 – 10	-6 to 6	V
CD Pin Voltage	$V_{CD}$	8 – 10	-0.3 to 6	V
VGL Pin Voltage	$V_{GL}$	11 – 10	-0.3 to $V_{REG} + 0.3$	V
REG Pin Source Current	$I_{REG}$	12 – 10	-10.0	mA
Voltage Between VB Pin and VS Pin	$V_B - V_S$	14 – 15	-0.3 to 20.0	V
VS Pin Voltage	$V_S$	15 – 10	-1 to 600	V
VGH Pin Voltage	$V_{GH}$	16 – 10	$V_S - 0.3$ to $V_B + 0.3$	V
Operating Ambient Temperature	$T_{OP}$	—	-40 to 85	°C
Storage Temperature	$T_{stg}$	—	-40 to 125	°C
Junction Temperature	$T_j$	—	150	°C

\* Surge voltage withstand (Human body model) of No.14, 15 and 16 is guaranteed 1000V. Other pins are guaranteed 2000 V.

## 2. Electrical Characteristics

Current polarities are defined as follows: current going into the IC (sinking) is positive current (+); and current coming out of the IC (sourcing) is negative current (-).

Unless otherwise specified,  $T_A$  is 25 °C,  $V_{CC}$  is 15 V.

Characteristic	Symbol	Conditions	Pins	Min.	Typ.	Max.	Unit
<b>Start Circuit and Circuit Current</b>							
Operation Start Voltage	$V_{CC(ON)}$		2 – 10	10.5	11.9	13.1	V
Operation Stop Voltage	$V_{CC(OFF)}$		2 – 10	9.0	10.0	11.1	V
Circuit Current in Operation	$I_{CC(ON)}$		2 – 10	—	—	10.0	mA
Circuit Current in Non-Operation	$I_{CC(OFF)}$	$V_{CC} = 10\text{ V}$	2 – 10	—	0.7	1.5	mA
Circuit Current in Protection	$I_{CC(P)}$	$V_{CC} = 12\text{ V}$	2 – 10	—	2.0	2.7	mA
Latched State Release VCC Pin Threshold Voltage	$V_{CC(L.OFF)}$		2 – 10	9.0	10.0	11.1	V
<b>Oscillator</b>							
Minimum Frequency	$f_{(MIN)}$		11 – 10 16 – 15	27.5	31.5	35.5	kHz
Maximum Frequency	$f_{(MAX)}$		11 – 10 16 – 15	230	300	380	kHz
Minimum Dead-Time	$t_{d(MIN)}$		11 – 10 16 – 15	0.04	0.24	0.44	μs
Maximum Dead-Time	$t_{d(MAX)}$		11 – 10 16 – 15	1.20	1.65	2.20	μs
Externally Adjusted Minimum Frequency 1	$f_{(MIN)ADJ1}$	$R_{CSS} = 30\text{ k}\Omega$	11 – 10 16 – 15	69	73	77	kHz
Externally Adjusted Minimum Frequency 2	$f_{(MIN)ADJ2}$	$R_{CSS} = 77\text{ k}\Omega$	11 – 10 16 – 15	42.4	45.4	48.4	kHz
<b>Feedback Control</b>							
FB Pin Oscillation Start Threshold Voltage	$V_{FB(ON)}$		3 – 10	0.15	0.30	0.45	V
FB Pin Oscillation Stop Threshold Voltage	$V_{FB(OFF)}$		3 – 10	0.05	0.20	0.35	V
FB Pin Maximum Source Current	$I_{FB(MAX)}$	$V_{FB} = 0\text{ V}$	3 – 10	-2.2	-1.6	-1.0	mA
FB Pin Reset Current	$I_{FB(R)}$	$V_{CC} = 10\text{ V}$ , $V_{FB} = 5.5\text{ V}$	3 – 10	3.5	7.0	11.5	mA
<b>Soft-start</b>							
CSS Pin Charging Current	$I_{CSS(C)}$		5 – 10	-120	-105	-90	μA
CSS Pin Reset Current	$I_{CSS(R)}$	$V_{CC} = 10\text{ V}$ , $V_{CSS} = 3\text{ V}$	5 – 10	1.1	1.8	2.5	mA
Maximum Frequency in Soft-start	$f_{(MAX)SS}$		11 – 10 16 – 15	400	500	600	kHz
<b>Dead Time</b>							
DTS Pin Voltage in Normal Operation	$V_{DTS(OP)}$		4 – 10	0	1	2	V
DTS Pin Threshold Voltage	$V_{DTS}$		4 – 10	—	1.9	—	V
DTS Pin Source Current	$I_{DTS}$	$V_{CC} = 10\text{ V}$ , $V_{DTS} = 0\text{ V}$	4 – 10	-12.0	-10.2	-8.5	μA
<b>Reset Detection</b>							
Maximum Reset Time	$t_{RST(MAX)}$		11 – 10 16 – 15	4	5	6	μs
<b>Driver Circuit Power Supply</b>							
REG Pin Output Voltage	$V_{REG}$		12 – 10	9.6	10.0	10.8	V

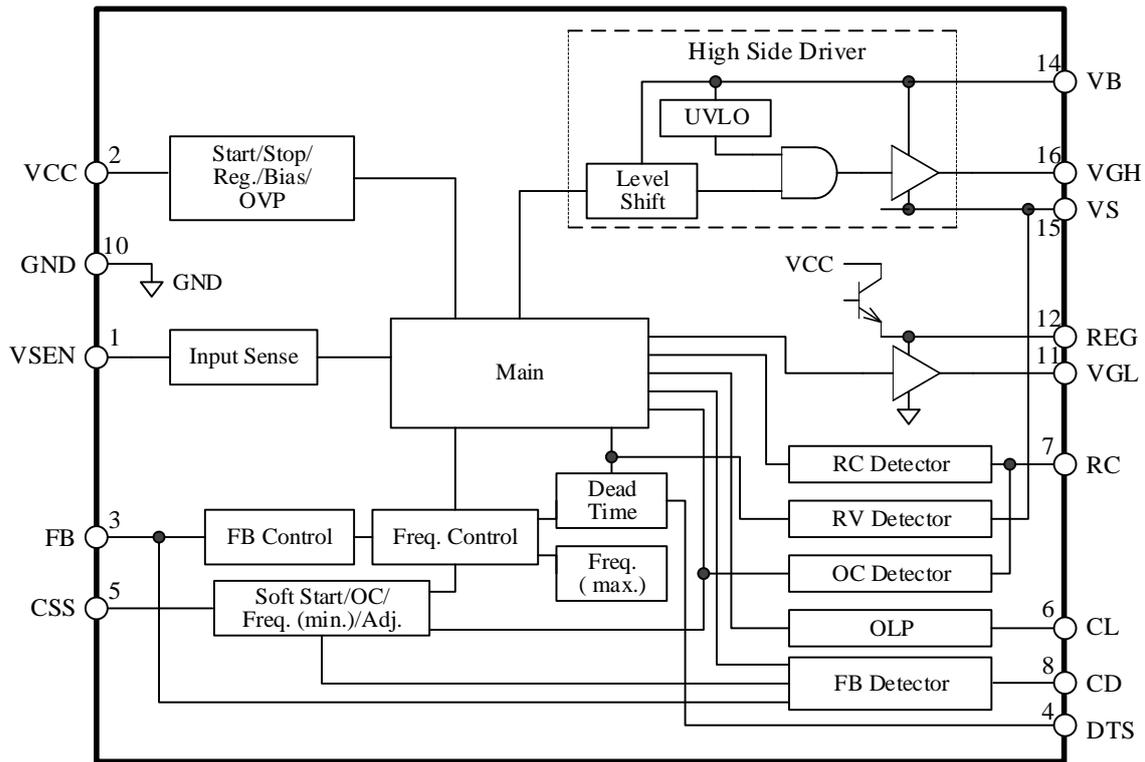
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Characteristic	Symbol	Conditions	Pins	Min.	Typ.	Max.	Unit
<b>High-side Driver</b>							
High-side Driver Operation Start Voltage	$V_{\text{BUV(ON)}}$		14 – 15	5.7	6.8	7.9	V
High-side Driver Operation Stop Voltage	$V_{\text{BUV(OFF)}}$		14 – 15	5.5	6.4	7.3	V
<b>Driver Circuit</b>							
VGL,VGH Pin Source Current 1	$I_{\text{GL(SRC)1}}$ $I_{\text{GH(SRC)1}}$	$V_{\text{REG}} = 10.5 \text{ V}$ , $V_{\text{B}} = 10.5 \text{ V}$ , $V_{\text{GL}} = 0 \text{ V}$ , $V_{\text{GH}} = 0 \text{ V}$	11 – 10 16 – 15	—	-540	—	mA
VGL,VGH Pin Sink Current 1	$I_{\text{GL(SNK)1}}$ $I_{\text{GH(SNK)1}}$	$V_{\text{REG}} = 10.5 \text{ V}$ , $V_{\text{B}} = 10.5 \text{ V}$ , $V_{\text{GL}} = 10.5 \text{ V}$ , $V_{\text{GH}} = 10.5 \text{ V}$	11 – 10 16 – 15	—	1.50	—	A
VGL,VGH Pin Source Current 2	$I_{\text{GL(SRC)2}}$ $I_{\text{GH(SRC)2}}$	$V_{\text{REG}} = 11.5 \text{ V}$ , $V_{\text{B}} = 11.5 \text{ V}$ , $V_{\text{GL}} = 10 \text{ V}$ , $V_{\text{GH}} = 10 \text{ V}$	11 – 10 16 – 15	-140	-90	-40	mA
VGL,VGH Pin Sink Current 2	$I_{\text{GL(SNK)2}}$ $I_{\text{GH(SNK)2}}$	$V_{\text{REG}} = 11.5 \text{ V}$ , $V_{\text{B}} = 11.5 \text{ V}$ , $V_{\text{GL}} = 1.5 \text{ V}$ , $V_{\text{GH}} = 1.5 \text{ V}$	11 – 10 16 – 15	140	230	360	mA
<b>VCC Pin Overvoltage Protection (VCC_OVP)</b>							
VCC Pin OVP Threshold Voltage	$V_{\text{CC(OVP)}}$		2 – 10	30.0	32.0	34.0	V
<b>Current Resonant and Overcurrent Protection(OCP)</b>							
Capacitive Mode Detection Voltage 1	$V_{\text{RC1}}$		7 – 10	0.02	0.10	0.18	V
				-0.18	-0.10	-0.02	V
Capacitive Mode Detection Voltage 2	$V_{\text{RC2}}$		7 – 10	0.20	0.30	0.40	V
				-0.40	-0.30	-0.20	V
RC Pin Threshold Voltage (Low)	$V_{\text{RC(L)}}$		7 – 10	1.80	1.90	2.00	V
				-2.00	-1.90	-1.80	V
RC Pin Threshold Voltage (High)	$V_{\text{RC(H)}}$		7 – 10	2.62	2.80	2.98	V
				-2.98	-2.80	-2.62	V
CSS Pin Sink Current (Low)	$I_{\text{CSS(L)}}$	$V_{\text{CSS}} = 3 \text{ V}$	5 – 10	1.1	1.8	2.5	mA
CSS Pin Sink Current (High)	$I_{\text{CSS(H)}}$	$V_{\text{CSS}} = 3 \text{ V}$	5 – 10	13.0	20.5	28.0	mA
<b>Overload Protection (OLP)</b>							
CL pin OLP Threshold Voltage	$V_{\text{CL(OLP)}}$		6 – 10	3.9	4.2	4.5	V
CL Pin Source Current 1	$I_{\text{CL(SRC)1}}$	$V_{\text{CL}} = 0.5 \text{ V}$	6 – 10	-29	-17	-5	$\mu\text{A}$
CL Pin Source Current 2	$I_{\text{CL(SRC)2}}$	$V_{\text{CL}} = 3 \text{ V}$	6 – 10	-180	-135	-90	$\mu\text{A}$
CL Pin Sink Current	$I_{\text{CL(SNK)}}$	$V_{\text{CL}} = 3 \text{ V}$	6 – 10	10	30	50	$\mu\text{A}$
<b>Input Overvoltage Protection (HVP), Input Undervoltage Protection (UVP)</b>							
VSEN Pin UVP Release Threshold Voltage	$V_{\text{SEN(ON)}}$		1 – 10	1.248	1.300	1.352	V
VSEN Pin UVP Threshold Voltage	$V_{\text{SEN(OFF)}}$		1 – 10	1.056	1.100	1.144	V
VSEN Pin HVP Threshold Voltage	$V_{\text{SEN(HVP)}}$		1 – 10	5.3	5.6	5.9	V
VSEN Pin Clamp Voltage	$V_{\text{SEN (CLAMP)}}$		1 – 10	10.0	—	—	V

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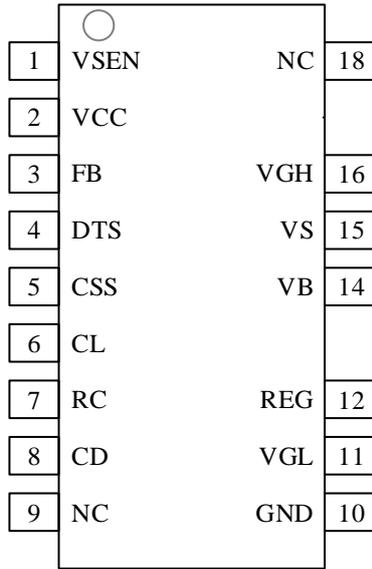
Characteristic	Symbol	Conditions	Pins	Min.	Typ.	Max.	Unit
<b>Optocoupler Open Protection (OOP)</b>							
FB Pin Open Detection Threshold Voltage	$V_{FB(OOP)}$		3 – 10	4.2	4.6	5.0	V
CD Pin Threshold Voltage	$V_{CD}$		8 – 10	2.8	3.0	3.2	V
CD Pin Source Current	$I_{CD(SRC)}$	$V_{CD} = 0\text{ V}$	8 – 10	-29	-20	-11	$\mu\text{A}$
CD Pin Sink Current	$I_{CD(SNK)}$	$V_{CD} = 2.5\text{ V}$	8 – 10	28	43	58	$\mu\text{A}$
CD Pin Reset Current	$I_{CD(R)}$	$V_{CD} = 2\text{ V}$	8 – 10	1.0	2.5	4.0	mA
<b>Thermal Shutdown (TSD)</b>							
Thermal Shutdown Temperature	$T_{j(TSD)}$		—	140	—	—	$^{\circ}\text{C}$
<b>Thermal Resistance</b>							
Junction to Ambient Thermal Resistance	$\theta_{j-A}$		—	—	—	95	$^{\circ}\text{C/W}$

## 3. Block Diagram



BD\_SSC3S931\_R1

4. Pin Configuration Definitions



Number	Name	Description
1	VSEN	Mains input voltage detection signal input
2	VCC	Supply voltage input for the IC with VCC pin overvoltage protection (VCC_OVP)
3	FB	Feedback signal input for constant voltage control and optocoupler open protection (OOP) signal input
4	DTS	Dead time control selection: a fixed on the minimum value, or an automatically adjustment
5	CSS	Soft-start setting capacitor connection
6	CL	Overload detection (OLP) capacitor connection
7	RC	Resonant current detection signal input and overcurrent protection (OCP) signal input
8	CD	Delay time setting capacitor connection for optocoupler open protection (OOP)
9	NC	Not connected
10	GND	Ground
11	VGL	Low-side gate drive output
12	REG	Supply voltage output for gate drive circuit
13	—	Pin removed
14	VB	Supply voltage input for high-side driver with UVLO
15	VS	Floating ground for high-side driver
16	VGH	High-side gate drive output
17	—	Pin removed
18	NC	Not connected

5. Typical Application

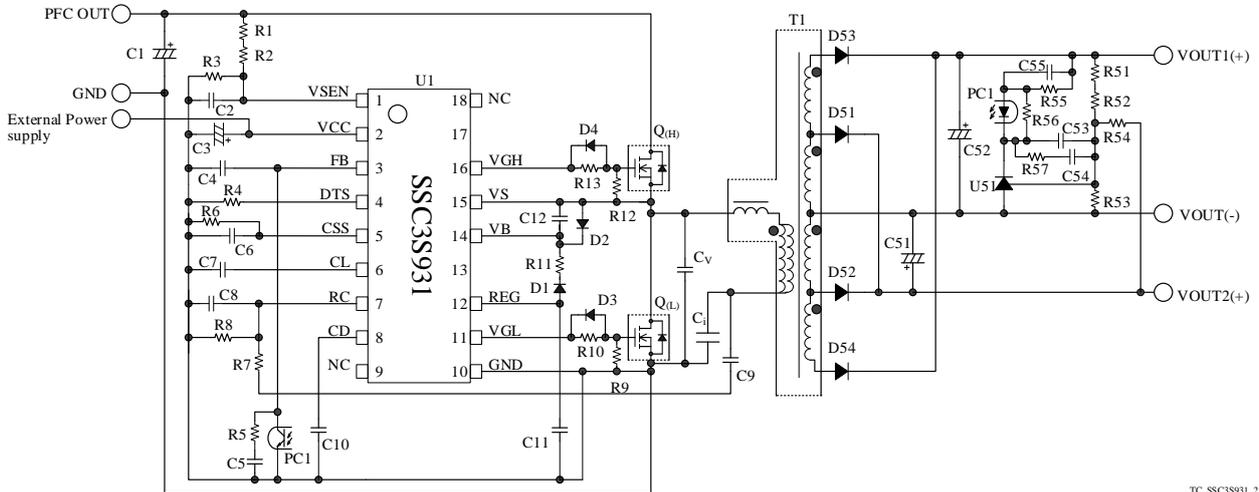
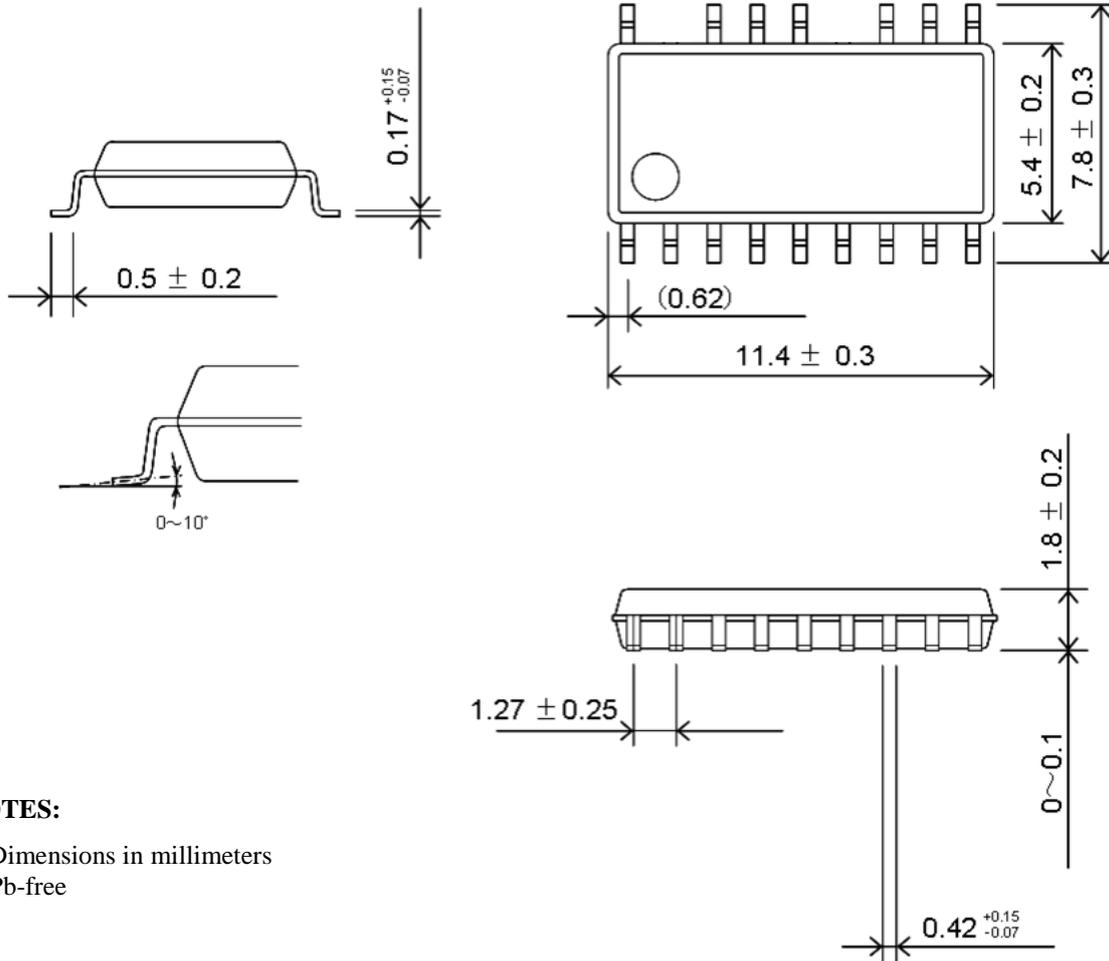


Figure 5-1. Typical Application

6. Physical Dimensions

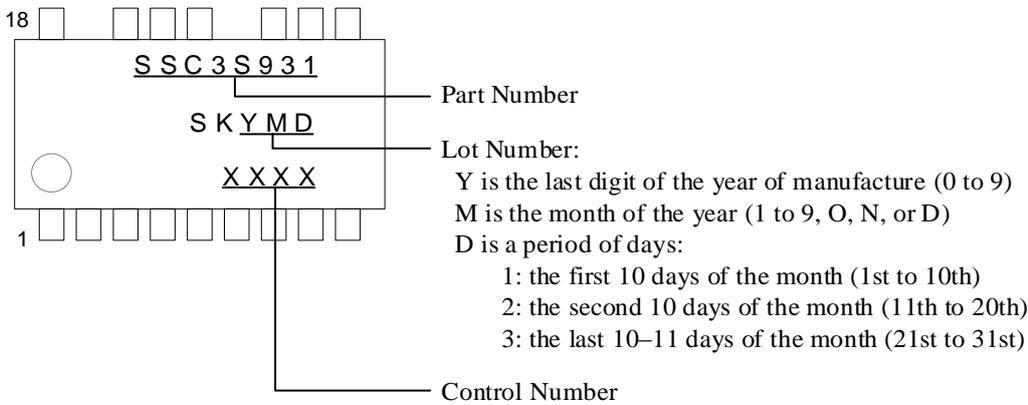
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NOTES:

- Dimensions in millimeters
- Pb-free

7. Marking Diagram



### 8. Operational Description

All of the parameter values used in these descriptions are typical values, unless they are specified as minimum or maximum. Current polarities are defined as follows: current going into the IC (sinking) is positive current (+); and current coming out of the IC (sourcing) is negative current (-). Q<sub>(H)</sub> and Q<sub>(L)</sub> indicate a high-side power MOSFET and a low-side power MOSFET respectively. C<sub>i</sub> and C<sub>v</sub> indicate a current resonant capacitor and a voltage resonant capacitor, respectively.

#### 8.1 Resonant Circuit Operation

Figure 8-1 shows a basic RLC series resonant circuit.

The impedance of the circuit, Ż, is as the following Equation.

$$\dot{Z} = R + j\left(\omega L - \frac{1}{\omega C}\right), \tag{1}$$

where ω is angular frequency; and ω = 2πf. Thus,

$$\dot{Z} = R + j\left(2\pi fL - \frac{1}{2\pi fC}\right). \tag{2}$$

When the frequency, f, changes, the impedance of resonant circuit will change as shown in Figure 8-2.

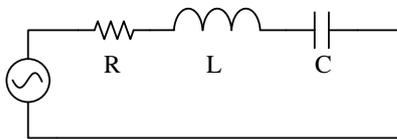


Figure 8-1. RLC Series Resonant Circuit

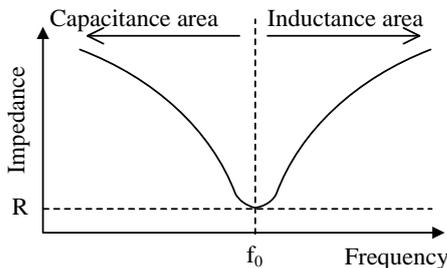


Figure 8-2. Impedance of Resonant Circuit

When 2πfL = 1/2πfC, Ż of Equation (2) becomes the minimum value, R (see Figure 8-2). In the case, ω is calculated by Equation (3).

$$\omega = 2\pi f = \frac{1}{\sqrt{LC}} \tag{3}$$

The frequency in which Ż becomes minimum value is called a resonant frequency, f<sub>0</sub>. The higher frequency area than f<sub>0</sub> is an inductance area. The lower frequency area than f<sub>0</sub> is a capacitance area.

From Equation (3), f<sub>0</sub> is as follows:

$$f_0 = \frac{1}{2\pi\sqrt{LC}}. \tag{4}$$

Figure 8-3 shows the circuit of a current resonant power supply. The basic configuration of the current resonant power supply is a half-bridge converter. The switching devices, Q<sub>(H)</sub> and Q<sub>(L)</sub>, are connected in series with V<sub>IN</sub>. The series resonant circuit and the voltage resonant capacitor, C<sub>v</sub>, are connected in parallel with Q<sub>(L)</sub>. The series resonant circuit is consisted of the following components: the resonant inductor, L<sub>R</sub>; the primary winding, P, of a transformer, T1; and the current resonant capacitor, C<sub>i</sub>. The coupling between the primary and secondary windings of T1 is designed to be poor so that the leakage inductance increases. This leakage inductance is used for L<sub>R</sub>. This results in a down sized of the series resonant circuit. The dotted mark with T1 describes the winding polarity, the secondary windings, S1 and S2, are connected so that the polarities are set to the same position as shown in Figure 8-3. In addition, the winding numbers of each other should be equal. From Equation (1), the impedance of a current resonant power supply is calculated by Equation (5). From Equation (4), the resonant frequency, f<sub>0</sub>, is calculated by Equation (6).

$$\dot{Z} = R + j\left\{\omega(L_R + L_P) - \frac{1}{\omega C_i}\right\}, \tag{5}$$

$$f_0 = \frac{1}{2\pi\sqrt{(L_R + L_P) \times C_i}}, \tag{6}$$

where:

R is the equivalent resistance of load,

L<sub>R</sub> is the inductance of the resonant inductor,

L<sub>P</sub> is the inductance of the primary winding P, and

C<sub>i</sub> is the capacitance of current resonant capacitor.

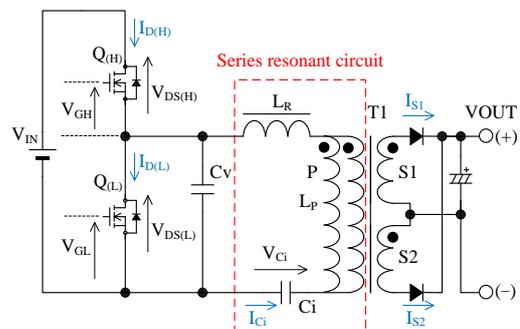


Figure 8-3. Current Resonant Power Supply Circuit

In the current resonant power supply,  $Q_{(H)}$  and  $Q_{(L)}$  are alternatively turned on and off. The on and off times of them are equal. There is a dead time between the on periods of  $Q_{(H)}$  and  $Q_{(L)}$ . During the dead time,  $Q_{(H)}$  and  $Q_{(L)}$  are in off status.

In the current resonant power supply, the frequency is controlled. When the output voltage decreases, the IC decreases the switching frequency so that the output power is increased to keep a constant output voltage. This must be controlled in the inductance area ( $f_{SW} > f_0$ ). Since the winding current is delayed from the winding voltage in the inductance area, the turn-on operates in a ZCS (Zero Current Switching); and the turn-off operates in a ZVS (Zero Voltage Switching). Thus, the switching losses of  $Q_{(H)}$  and  $Q_{(L)}$  are nearly zero. In the capacitance area ( $f_{SW} < f_0$ ), the current resonant power supply operates as follows: When the output voltage decreases, the switching frequency is more decreased; and then, the output power is more decreased. Therefore, the output voltage cannot be kept constant. Since the winding current goes ahead of the winding voltage in the capacitance area,  $Q_{(H)}$  and  $Q_{(L)}$  operate in the hard switching. This results in the increases of a power loss. This operation in the capacitance area is called the capacitive mode operation. The current resonant power supply must be operated without the capacitive mode operation (for more details, see Section 8.8).

Figure 8-4 describes the basic operation waveform of current resonant power supply (see Figure 8-3 about the symbol in Figure 8-4). For the description of current resonant waveforms in normal operation, the operation is separated into a period A to F. In the following description:

- $I_{D(H)}$  is the current of  $Q_{(H)}$ ,
- $I_{D(L)}$  is the current of  $Q_{(L)}$ ,
- $V_{F(H)}$  is the forward voltage of  $Q_{(H)}$ ,
- $V_{F(L)}$  is the forward voltage of  $Q_{(L)}$ ,
- $I_L$  is the current of  $L_R$ ,
- $V_{IN}$  is an input voltage,
- $V_{Ci}$  is  $C_i$  voltage, and
- $V_{Cv}$  is  $C_v$  voltage.

The current resonant power supply operations in period A to F are as follows:

1) Period A

When  $Q_{(H)}$  is on, an energy is stored into the series resonant circuit by  $I_{D(H)}$  that flows through the resonant circuit and the transformer (see Figure 8-5). At the same time, the energy is transferred to the secondary circuit. When the primary winding voltage can not keep the on status of the secondary rectifier, the energy transmission to the secondary circuit is stopped.

2) Period B

After the secondary side current becomes zero, the

resonant current flows to the primary side only to charge  $C_i$  (see Figure 8-6).

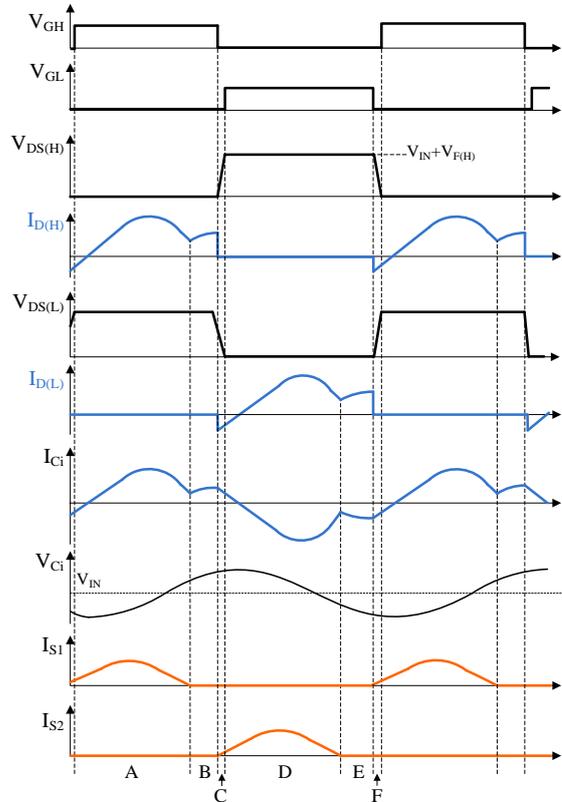


Figure 8-4. The Basic Operation Waveforms of Current Resonant Power Supply

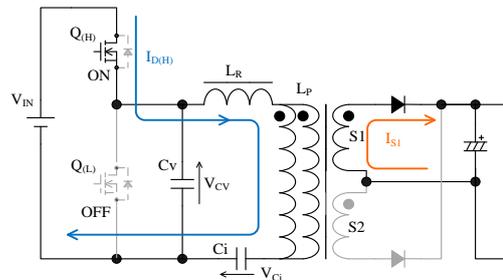


Figure 8-5. Operation in period A

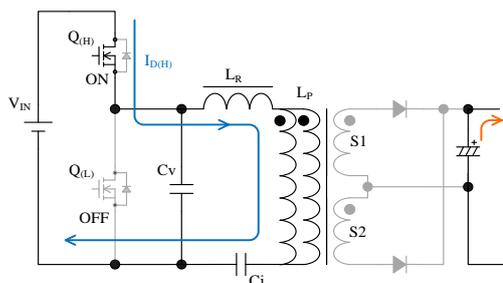


Figure 8-6. Operation in Period B

3) Period C

C is the dead-time period.  $Q_{(H)}$  and  $Q_{(L)}$  are in off status. When  $Q_{(H)}$  turns off,  $C_V$  is discharged by  $I_L$  that is supplied by the energy stored in the series resonant circuit applies (see Figure 8-7). When  $V_{C_V}$  decreases to  $V_{F(L)}$ ,  $-I_{D(L)}$  flows through the body diode of  $Q_{(L)}$ ; and  $V_{C_V}$  is clamped to  $V_{F(L)}$ . After that,  $Q_{(L)}$  turns on. Since  $V_{DS(L)}$  is nearly zero at the point,  $Q_{(L)}$  operates in the ZVS and the ZCS; thus, the switching loss achieves nearly zero.

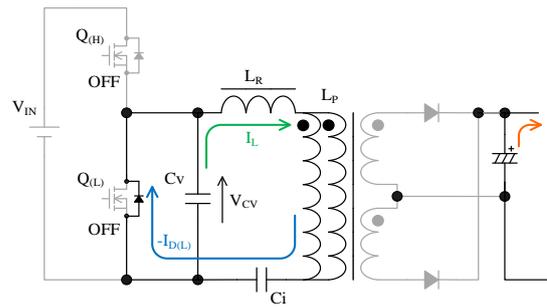


Figure 8-7. Operation in Period C

4) Period D

When  $Q_{(L)}$  turns on,  $I_{D(L)}$  flows as shown in Figure 8-8; and  $V_{C_i}$  is applied the primary winding voltage of the transformer. At the same time, energy is transferred to the secondary circuit. When the primary winding voltage can not keep the on status of the secondary rectifier, the energy transmission to the secondary circuit is stopped.

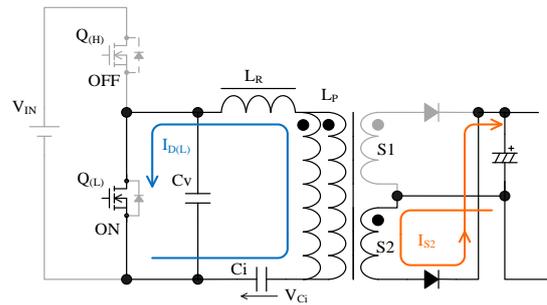


Figure 8-8. Operation in Period D

5) Period E

After the secondary side current becomes zero, the resonant current flows to the primary side only to charge  $C_i$  (see Figure 8-9).

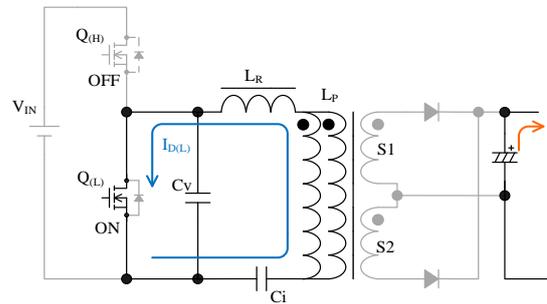


Figure 8-9. Operation in Period E

6) Period F

F is the dead-time period.  $Q_{(H)}$  and  $Q_{(L)}$  are in off status.

When  $Q_{(L)}$  turns off,  $C_V$  is charged by  $-I_L$  that is supplied by the energy stored in the series resonant circuit applies (see Figure 8-10). When  $V_{C_V}$  increases to  $V_{IN} + V_{F(H)}$ ,  $-I_{D(H)}$  flows through body diode of  $Q_{(H)}$ ; and  $V_{C_V}$  is clamped to  $V_{IN} + V_{F(H)}$ . After that,  $Q_{(H)}$  turns on. Since  $V_{DS(H)}$  is nearly zero at the point,  $Q_{(H)}$  operates in the ZVS and the ZCS; thus, the switching loss achieves nearly zero.

After the period F,  $I_{D(H)}$  flows again; and the operation returns to the period A. The above operation is repeated to transfer energy to the secondary side from the resonant circuit.

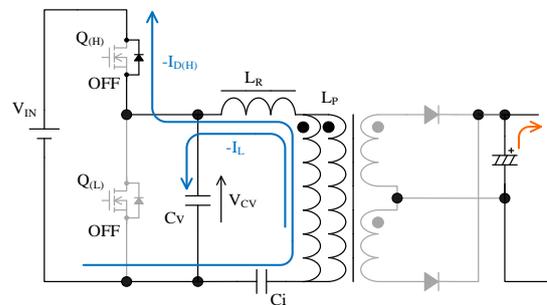


Figure 8-10. Operation in Period F

### 8.2 Startup Operation

Figure 8-11 and Figure 8-12 show the VCC pin peripheral circuit and the startup waveforms, respectively. The VCC pin is a power supply input pin for a control circuit and is supplied from an external power supply. When the VCC pin voltage increases to the Operation Start Voltage,  $V_{CC(ON)} = 11.9\text{ V}$ , the control circuit starts operation. When the VCC pin voltage decreases to the Operation Stop Voltage,  $V_{CC(OFF)} = 10.0\text{ V}$ , the control circuit is stopped by the undervoltage lockout (UVLO) circuit, and returns to the state before startup (see Figure 8-13).

When the IC satisfies all following conditions, the IC starts a switching operation:

- VCC pin voltage  $\geq V_{CC(ON)} = 11.9\text{ V}$
- VSEN pin voltage  $\geq V_{SEN(ON)} = 1.300\text{ V}$
- FB pin voltage  $\geq V_{FB(ON)} = 0.30\text{ V}$

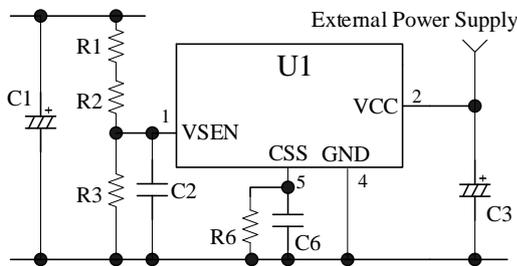


Figure 8-11. VCC Pin Peripheral Circuit

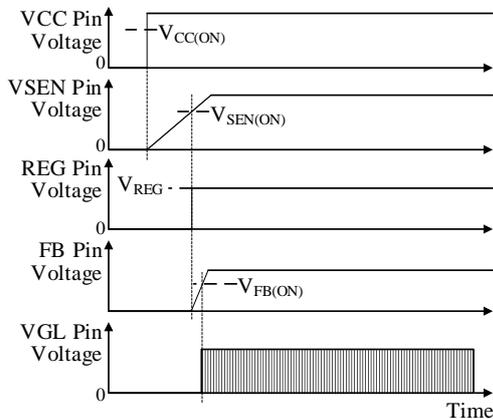


Figure 8-12. Startup Waveforms

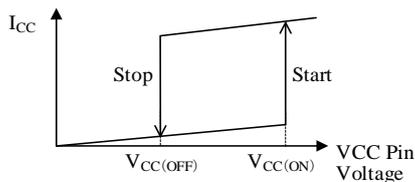


Figure 8-13.  $V_{CC}$  vs.  $I_{CC}$

### 8.3 Soft Start Function

Figure 8-14 shows the soft start operation waveforms.

The IC has the soft start function to reduce stress of peripheral component, and to prevent the capacitive mode operation. During the soft start operation, C6 connected to the CSS pin is charged by the CSS Pin Charge Current,  $I_{CSS(C)} = -105\ \mu\text{A}$ . The oscillation frequency is varied according to the CSS pin voltage. The switching frequency ( $f_{(MAX)SS}^* = 500\text{ kHz}$  is maximum) gradually decreases according to rise the CSS pin voltage; at same time, output power increases. The IC operates with an oscillation frequency control that uses feedback signal after the output power increases. When the IC becomes any of the following conditions, C6 is discharged by the CSS Pin Reset Current,  $I_{CSS(R)} = 1.8\text{ mA}$ .

- When the VCC pin voltage decreases to the operation stop voltage,  $V_{CC(OFF)} = 10.0\text{ V}$ , or less.
- When VSEN pin voltage is  $V_{SEN(OFF)} = 1.100\text{ V}$  or less.
- When one or more following corresponding protections are activated: VCC\_OVP, HVP, OLP, OOP, or TSD.

During the soft start operation, a CD pin voltage also increases. The CD pin voltage is used for the optocoupler open protection (OOP). Note that a startup failure may be occurred due to the OOP activation when the soft start period is too long. See the Section 8.14 for setting of C10 connected to the CD pin.

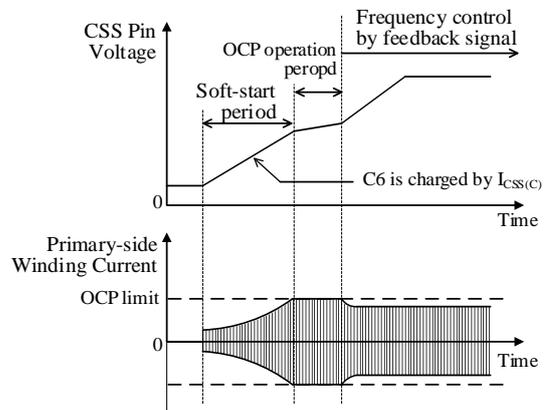


Figure 8-14. Soft Start Operation

\* The maximum frequency during normal operation is  $f_{(MAX)} = 300\text{ kHz}$ .

### 8.4 Minimum and Maximum Switching Frequency Setting

The minimum switching frequency is determined by the resistance of R6 connected to the CSS pin. Figure 8-15 shows the relationship of R6 and  $f_{(MIN)ADJ}$  that is the external adjustment minimum frequency.

The  $f_{(MIN)ADJ}$  must be set more than the resonant frequency,  $f_0$ , under the condition of the minimum mains input voltage and the maximum output power. The maximum switching frequency,  $f_{MAX}$ , is determined by the inductance and the capacitance of a resonant circuit. The  $f_{MAX}$  must be set less than the maximum frequency,  $f_{(MAX)} = 300$  kHz.

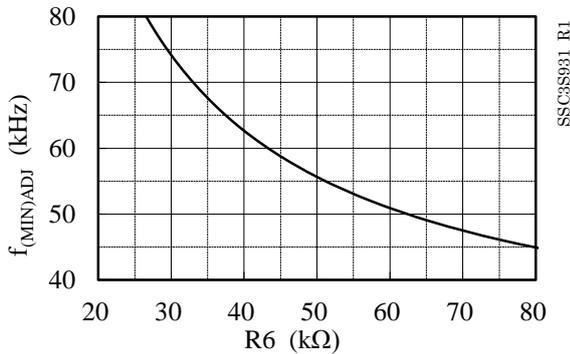


Figure 8-15. R6 vs.  $f_{(MIN)ADJ}$

### 8.5 High-side Driver

Figure 8-16 shows the bootstrap circuit that drives  $Q_{(H)}$ , and is configured by D1, R11, and C12 (between the REG and VS pins).

When the  $Q_{(H)}$  and  $Q_{(L)}$  are an off and on statuses, the VS pin voltage becomes about ground level; and C12 is charged from the REG pin.

When the voltage between the VB and VS pins,  $V_{B-S}$ , increases to  $V_{BUV(ON)} = 6.8$  V or more, an internal high-side drive circuit starts an operation. When  $V_{B-S}$  decreases to  $V_{BUV(OFF)} = 6.4$  V or less, the high-side drive circuit stops the operation. In case the both ends of C12 and D2 are shorted, the IC is protected by  $V_{BUV(OFF)}$ . D2 is for the protection against negative voltage of the VS pin

- D1  
D1 should be an ultrafast recovery diode of short recovery time and low reverse current. When the maximum mains input voltage of the application is 265VAC, it is recommended to use ultrafast recovery diode of  $V_{RM} = 600$  V
- C11, C12, and R11  
The values of C11, C12, and R11 are determined by total gate charge,  $Q_g$ , of external MOSFET and

voltage dip amount between the VB and VS pins in the minimum frequency operation.

C11, C12, and R11 should be adjusted so that the voltage between the VB pin and the VS is more than  $V_{BUV(ON)} = 6.8$  V by measuring the voltage with a high-voltage differential probe.

The reference value of C11 is  $0.47\mu\text{F}$  to  $1\mu\text{F}$ .

The time constant of C12 and R11 should be less than 500 ns. The value of C12 is  $0.047\mu\text{F}$  to  $0.1\mu\text{F}$ . The value of R11 is  $2.2\Omega$  to  $10\Omega$ .

C11 and C12 should be a film or a ceramic capacitor that has a low ESR and a low leakage current characteristics.

- D2  
D2 should be a Schottky diode that has a low forward voltage characteristics to avoid that  $V_{B-S}$  is  $-0.3$  V or less, i.e., to use within its absolute maximum rating value.

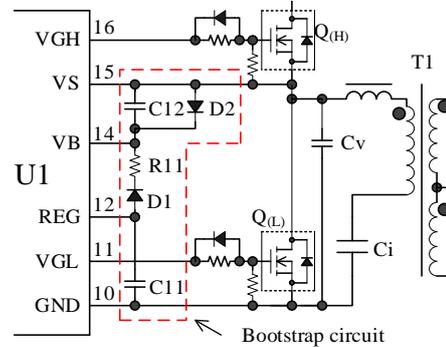


Figure 8-16. Bootstrap Circuit

### 8.6 Constant Voltage Control Operation

Figure 8-17 shows the FB pin peripheral circuit.

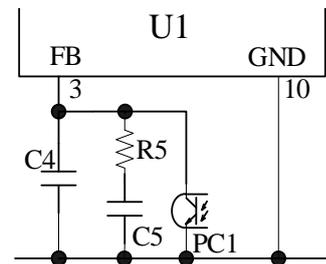


Figure 8-17. FB Pin Peripheral Circuit

The FB pin is sunk the feedback current by the photo-coupler, PC1, connected to the FB pin. As a result, the oscillation frequency is controlled to constant output voltage by the FB pin (in inductance area). Under slight load condition, the feedback current increases; and the FB pin voltage decreases. While the FB pin voltage decreases to the oscillation stop threshold voltage,

$V_{FB(OFF)} = 0.20$  V, or less, the IC stops switching operation. This operation reduces switching loss, and prevents the increasing of the secondary output voltage.

R5 and C5 are for a phase compensation adjustment. C4 is for a high frequency noise rejection. The secondary-side circuit should be designed so that the collector current of PC1 is  $>1.6$  mA that is the absolute value of the maximum source current,  $I_{FB(MAX)}$ . Especially, the current transfer ratio, CTR, of the photo coupler should be taken an aging degradation into account.

### 8.7 Dead Time Adjustment Function

The dead time is the period when both the high-side and the low-side power MOSFETs are off. If the dead time is shorter than a voltage resonant period (see Figure 8-18), the power MOSFETs turns on/off during the voltage resonant operation. In the case, the switching loss increases due to hard switching operation of the power MOSFETs.

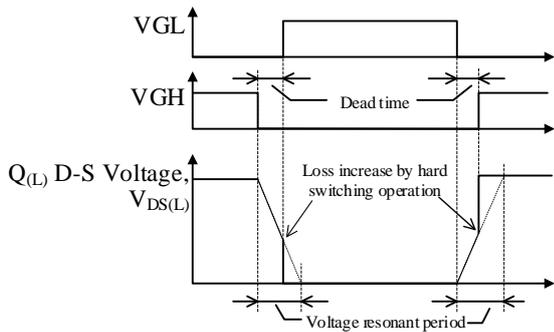


Figure 8-18. ZVS Failure Operation Waveform

The dead time setting (a fixed minimum value or an automatically adjustment value) is determined by the DTS pin voltage at the startup. To set to the fixed dead time, apply  $V_{DTS}$  of 1.9 V or more to the DTS pin and start the IC. To automatically adjust a dead time by the internal IC, apply less than  $V_{DTS}$  to the DTS pin (e.g., pulls down the DTS pin by the register of about 100 k $\Omega$ ) and start the IC. The source current  $I_{DTS} = -10.2$   $\mu$ A flows through the DTS pin. The slope of the DTS pin voltage in the startup is adjusted by a register and/or capacitor connected to the DTS pin.

This automatic dead time adjustment function operates so that the IC detects a voltage resonant period to automatically control the ZVS (Zero Voltage Switching) operation of  $Q_{(H)}$  and  $Q_{(L)}$ . This function achieves the power supply application without a dead time adjustment for each power supply specification, if the voltage resonant period is varied according to the power supply specifications such as an input voltage and an output power. The VS pin detects the  $dv/dt$  periods on the rising and falling voltage waveforms between

drain and source of the low-side power MOSFET (see Figure 8-19). The dead time is determined the detected  $dv/dt$  period. As a result, the high-side and the low-side power MOSFETs are automatically controlled in the Zero Voltage Switching (ZVS) operation. This function operates in the period from  $t_{d(MIN)} = 0.24$   $\mu$ s to  $t_{d(MAX)} = 1.65$   $\mu$ s. Check that the Zero Current Switching (ZCS) operation period is about 600 ns (i.e., the period that the drain current flows through the body diode as shown in Figure 8-20) based on actual operation in the following conditions:

- When an output power is minimum in a maximum input voltage specification.
- When an output power is maximum in a minimum input voltage specification.

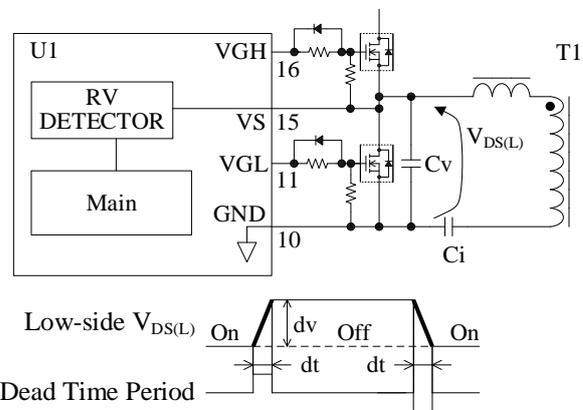


Figure 8-19. VS Pin and Dead Time Period

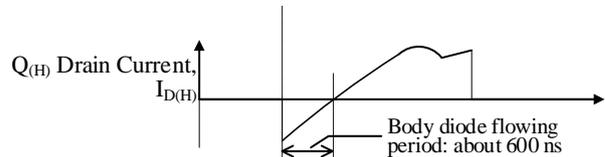


Figure 8-20. ZCS Check Point

### 8.8 Capacitive Mode Detection Function

The resonant power supply should be operated in the inductance area shown in Figure 8-21. In the capacitance area, the power supply becomes the capacitive mode operation (see Section 8.1). To prevent the operation, the minimum oscillation frequency must be set higher than  $f_0$  on each power supply specification. The IC has the capacitive mode operation detection function to keep the frequency always higher than  $f_0$ . Thus, the minimum oscillation frequency setting is unnecessary; and the power supply design is easier. In addition, the ability of transformer is improved because the operating frequency can be close to the resonant frequency,  $f_0$ .

The resonant current is detected by the RC pin to prevent the capacitive mode operation. When the capacitive mode is detected, the C7 connected to the CL

pin is charged by  $I_{CL(SRC)1} = -17 \mu A$ . When the CL pin voltage increases to  $V_{CL(OLP)}$ , the OLP is activated to stop the switching operation in latched state. The detection voltage is changed  $V_{RC1} = \pm 0.10 V$  or  $V_{RC2} = \pm 0.30 V$  depending on the load (see Figure 8-23 and Figure 8-24).

The capacitive mode operation detection function operations as follows:

•  **$Q_{(H)}$  On Period**

Figure 8-22 shows the RC pin waveform in the inductance area. Figure 8-23 and Figure 8-24 show the RC pin waveform in the capacitance area.

In the inductance area, the RC pin voltage does not cross  $+V_{RCx}$  from higher to lower during the  $Q_{(H)}$  on period (see Figure 8-22). On the contrary, in the capacitance area, the RC pin voltage crosses  $+V_{RC1}$  from higher to lower. At this point, the capacitive mode operation is detected. Then,  $Q_{(H)}$  is turned off; and  $Q_{(L)}$  is turned on (see Figure 8-23 and Figure 8-24).

•  **$Q_{(L)}$  On Period**

Contrary to the case of  $Q_{(H)}$ , in the capacitance area, the RC pin voltage crosses  $-V_{RCx}$  from lower to higher during the  $Q_{(L)}$  on period. At this point, the capacitive mode operation is detected. Then,  $Q_{(L)}$  is turned off; and  $Q_{(H)}$  is turned on.

As above, to prevent the capacitive mode, the RC pin voltage is detected by pulse-by-pulse; and an operating frequency is synchronized with a capacitive mode operation frequency. C9, R7, and R8 should be set as follows:

- The absolute value of the RC pin voltage is more than  $|V_{RC2}| = 0.30 V$ ; and
- The RC pin voltage must be within the absolute maximum ratings of  $-6$  to  $6 V$ .

In addition, to set C9, R7, and R8, the settings described in Section 8.12 and the condition that the capacitive mode is easily caused (e.g., startup, turning off the mains input voltage, or output shorted) should be taken into account.

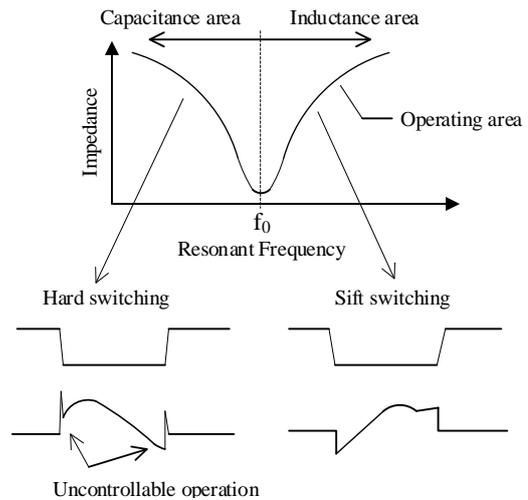


Figure 8-21. Operating Area of Resonant Power Supply

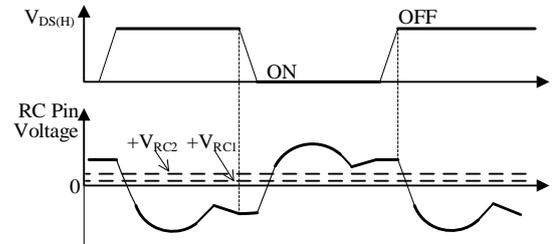


Figure 8-22. RC Pin Voltage in Inductance Area

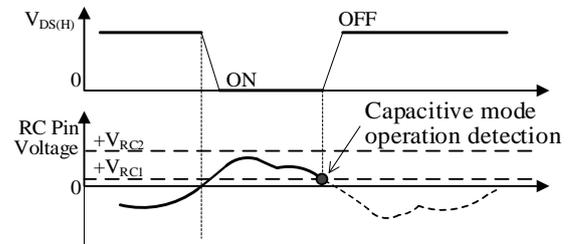


Figure 8-23. High-side Capacitive Mode Detection in Light Load

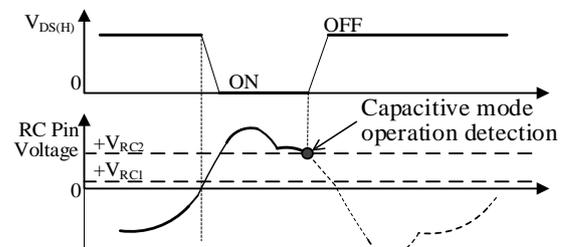


Figure 8-24. High-side Capacitive Mode Detection in Heavy Load

### 8.9 Reset Detection Function

In the startup period, the feedback control for the output voltage is inactive. If a magnetizing current may not be reset in the on-period because of unbalanced operation, a negative current may flow just before a power MOSFET turns off. This causes a hard switching operation, increases the stresses of the power MOSFET. Where the magnetizing current means the circulating current applied for resonant operation, and flows only into the primary-side circuit. To prevent the hard switching, the IC has the reset detection function.

Figure 8-26 shows the high-side operation and the reference drain current waveforms in a normal resonant operation and a reset failure operation. To prevent the hard switching operation, the reset detection function operates such as an on period is extended until the absolute value of a RC pin voltage,  $|V_{RC1}|$ , increases to 0.10 V or more. When the on period reaches the maximum reset time,  $t_{RST(MAX)} = 5 \mu s$ , the on-period expires at that moment, i.e., the power MOSFET turns off (see Figure 8-25).

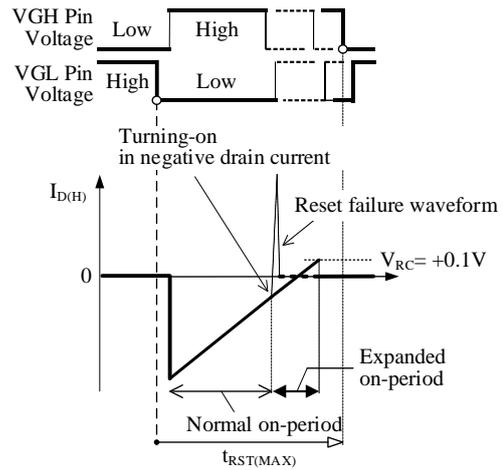


Figure 8-25. Reset Detection Operation Example at High-side On Period

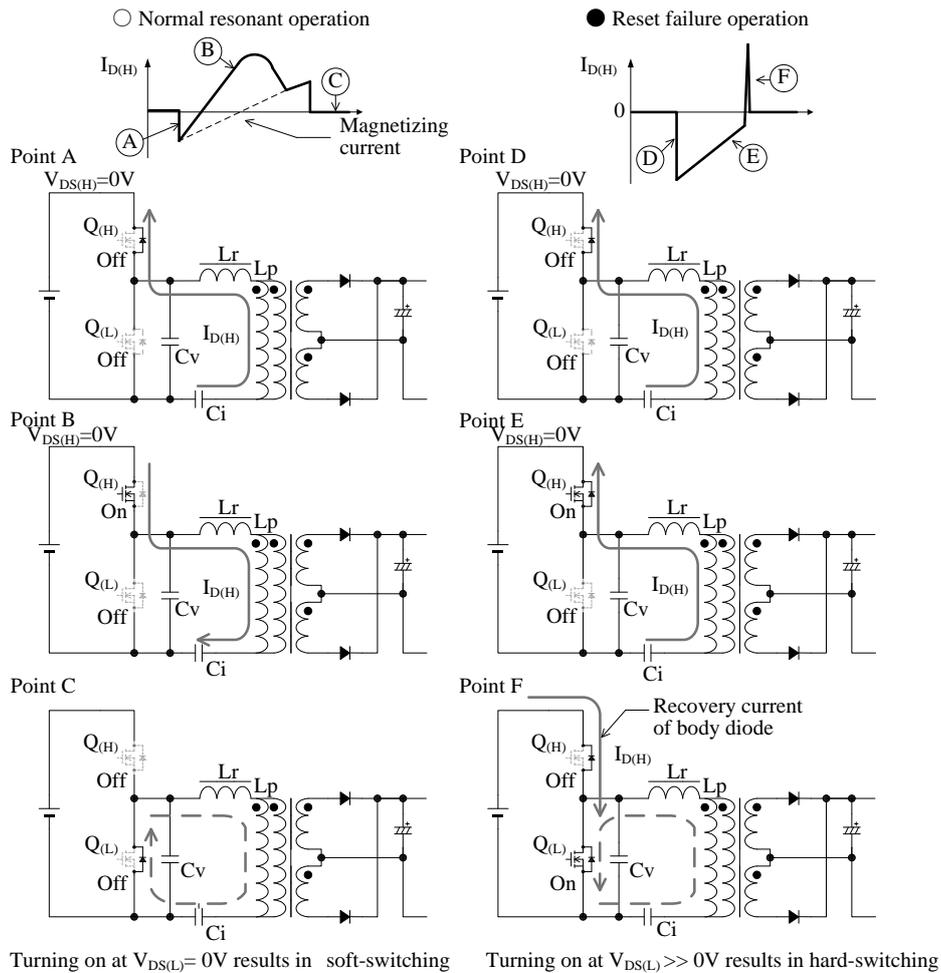


Figure 8-26. Reference High-side Operation and Drain Current Waveforms in Normal Resonant Operation and in Reset Failure Operation

### 8.10 VCC Pin Overvoltage Protection (VCC\_OVP)

When the voltage between the VCC and GND pins is applied to the VCC Pin OVP Threshold Voltage,  $V_{CC(OVP)} = 32.0\text{ V}$ , or more, the VCC pin overvoltage protection (VCC\_OVP) is activated; and the IC stops switching operation in a latched state. To release the latched state, decrease the VCC pin voltage to  $\leq V_{CC(L,OFF)}$  of 10.0 V, or decrease the VSEN pin voltage to  $\leq V_{SEN(OFF)}$  of 1.100 V, respectively.

The VCC pin input voltage must be set less than the its absolute maximum rating of 35 V.

### 8.11 Input Overvoltage Protection (HVP), Input Undervoltage Protection (UVP)

When the VSEN pin voltage reaches  $V_{SEN(HVP)}$  of 5.6 V or more due to the increasing input voltage from a steady state, the input overvoltage protection (HVP) is activated; and the IC stops switching operation in a latched state. To release the latched state, decrease the VCC pin voltage to  $\leq V_{CC(L,OFF)}$  of 10.0 V, or decrease the VSEN pin voltage to  $\leq V_{SEN(OFF)}$  of 1.100 V, respectively.

On the other hand, when the VSEN pin voltage falls to  $V_{SEN(OFF)}$  of 1.100 V or less due to the decreasing input voltage from a steady state, the input under voltage protection (UVP) is activated; and the IC stops the switching operation. Even if the IC is in the operating state (e.g., the VCC pin voltage is more than  $V_{CC(OFF)}$ ), the UVP is prevailed, and is activated.

When the VSEN pin voltage increases to  $V_{SEN(ON)} = 1.300\text{ V}$  or more depending on input voltage rising in the operating state, the IC restarts the switching operation. The DC input voltage at the HVP or the UVP activation is calculated as follows:

$$V_{IN(OP)} = V_{SEN(TH)} \times \left(1 + \frac{R1 + R2}{R3}\right) \tag{7}$$

Where  $V_{IN(OP)}$  is the DC input voltage at the HVP or the UVP activation, and  $V_{SEN(TH)}$  is the threshold voltage of the VSEN pin (see Table 8-1).

Table 8-1. VSEN Pin Threshold Voltage

Parameter	Symbol	$V_{SEN(TH)}$
VSEN Pin HVP Threshold Voltage	$V_{SEN(HVP)}$	5.6 V
VSEN Pin UVP Threshold Voltage	$V_{SEN(OFF)}$	1.100 V
VSEN Pin UVP Release Threshold Voltage	$V_{SEN(ON)}$	1.300 V

R1 and R2 have a high resistance, and are applied high voltage. Thus, these should be taken into account as follows:

- Select a resistor designed against electromigration according to the specifications of the application.
- Use a combination of resistors in series for that to reduce each applied voltage.

R1 reference value is about 10 MΩ. C2 shown in Figure 8-27 is for reducing noises, and is set 1000 pF to 0.01 μF. The value of R1, R2, R3, and C2 should be selected based on actual operation in the application.

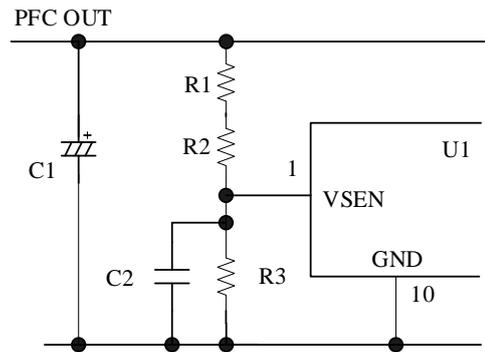


Figure 8-27. VSEN Pin Peripheral Circuit

### 8.12 Overcurrent Protection (OCP)

For the overcurrent protection (OCP), the IC detects the drain current,  $I_D$ , on pulse-by-pulse basis, and limits output power. the OCP circuit achieves that C9 value can be smaller than Ci value. Where C9 is for shunt capacitor, and Ci is for current resonant capacitor (see Figure 8-28). This results in the reducing detection current through C9. Thus, the loss of the detection resistor, R8, is reduced; and the size of R8 can be smaller.

There is no convenient method that the accurate resonant current value is calculated using the parameter such as condition of a mains input or an output. Thus, C9, R7, and R8 should be adjusted based on actual operation in the application. The reference values for C8, C9, R7, and R8 and their adjustment methods are as follows:

- R8 and C9  
 C9: 100pF to 330pF (around 1 % of Ci value).  
 R8: Around 100 Ω.  
 R8 is calculated Equation (8). The detection voltage of R8 is used the detection of the capacitive mode operation (see Section 8.8). Therefore, setting of R8 and C9 should be taken account of both OCP and the capacitive mode operation.

$$R8 \approx \frac{|V_{RC(L)}|}{I_{D(H)}} \times \left(\frac{C9 + Ci}{C9}\right) \tag{8}$$

Where  $I_{D(H)}$  is the current of the high-side power

MOSFET at an on state, and  $V_{RC(L)}$  is the RC Pin Threshold Voltage (Low) of  $\pm 1.90$  V

- R7 and C8  
They are for high frequency noise reduction.  
R7: 100  $\Omega$  to 470  $\Omega$   
C8: 100 pF to 1000 pF

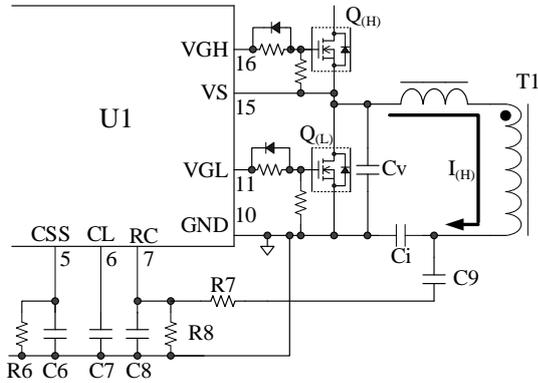


Figure 8-28. RC Pin Peripheral Circuit

The OCP operation has two level threshold voltages as follows:

### 8.12.1 Overcurrent Protection 1 (OCP1)

This is a first OCP level. When the absolute value of the RC pin voltage increases to more than  $|V_{OC(L)}|$  of 1.90 V, C6 connected to the CSS pin is discharged by  $I_{CSS(L)} = 1.8$  mA. Thus, the switching frequency increases to prevent the output power rising. When the absolute value of the RC pin voltage decreases to  $|V_{RC(L)}|$  or less during the C6 discharge, the C6 discharge is stopped.

### 8.12.2 Overcurrent Protection 2 (OCP2)

This is a second OCP level. When the absolute value of the RC pin voltage increases to more than  $|V_{RC(H)}| = 2.80$  V, the high speed OCP is activated. Then, the on/off statuses of power MOSFETs are inverted. At the same time, C6 is discharged by  $I_{CSS(H)} = 20.5$  mA. Thus, the switching frequency quickly increases to quickly prevent the output power rising. The OCP2 protects the IC from the exceeding overcurrent caused by the abnormal condition such as the output shorted.

When the absolute value of the RC pin voltage decreases to  $|V_{RC(H)}|$  or less, the OCP level is transferred to OCP1 operation.

## 8.13 Overload Protection (OLP)

Figure 8-29 shows the overload protection (OLP) waveforms. When increasing of an output power and the overcurrent protection 1 (OCP1) is activated, the C7 connected to the CL pin is charged by  $I_{CL(SRC)1}$  of  $-17$   $\mu$ A. Moreover, when the overcurrent protection 2 (OCP2) is activated, the C7 connected to the CL pin is charged by  $I_{CL(SRC)2}$  of  $-135$   $\mu$ A. When the CL pin voltage increases to  $V_{CL(OLP)}$  of 4.2 V due to maintaining the OCP1 or OCP2 operations, the OLP is activated, and the switching operation stops in a latched state. To release the latched state, decrease the VCC pin voltage to  $\leq V_{CC(L,OFF)}$  of 10.0 V, or decrease the VSEN pin voltage to  $\leq V_{SEN(OFF)}$  of 1.100 V, respectively.

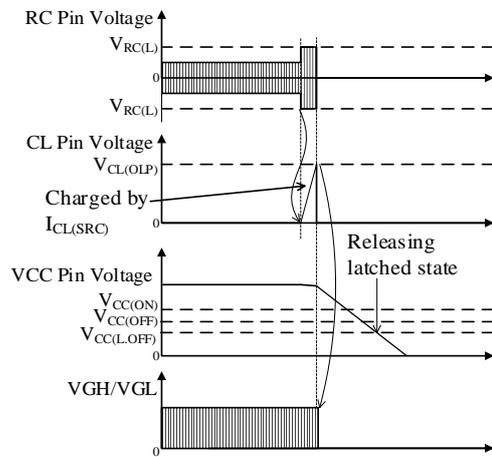


Figure 8-29. OLP Waveform

## 8.14 Optocoupler Open Protection (OOP)

In case the primary side of an optocoupler becomes open, a feedback current reduction due to the FB pin voltage rising result in the output voltage increases. To prevent the status the IC has the optocoupler open protection (OOP). The OOP is activated at following condition.

- When the FB pin voltage increases to higher than the CSS pin voltage, or
- When the FB pin voltage increases to the FB Pin Open Detection Threshold Voltage,  $V_{FB(OOP)} = 4.6$  V, or more.

After the OOP activation, C10 connected to the CD pin is charged by the CD Pin Source Current,  $I_{CD(SRC)} = -20$   $\mu$ A. When the CD pin voltage increases to the CD Pin Threshold Voltage,  $V_{CD} = 3.0$  V, the IC stops switching operation in a latched state. To release the latched state, decrease the VCC pin voltage to  $\leq V_{CC(L,OFF)}$  of 10.0 V, or decrease the VSEN pin voltage to  $\leq V_{SEN(OFF)}$  of 1.100 V, respectively.

The delay time is period until the switching operation stop from the OOP activation. The maximum delay time,  $t_{DLY\_MAX}$ , is calculated by following equation.

$$t_{DLY\_MAX} = \frac{V_{CD} \times C_{CD}}{|I_{CD(SRC)}|}, \quad (9)$$

where:

$V_{CD}$  is the CD Pin Threshold Voltage of 3.0 V,

$C_{CD}$  is the value of C10 connected to the CD pin (about 0.1  $\mu$ F to 0.47  $\mu$ F), and

$I_{CD(SRC)}$  is the CD Pin Source Current of  $-20 \mu$ A.

If C10 = 0.1  $\mu$ F,

$$t_{DLY\_MAX} = \frac{3.0 \text{ V} \times 0.1 \mu\text{F}}{|-20 \mu\text{A}|} = 15 \text{ ms}.$$

During startup operation (see Section 8.3), the CD pin voltage increases because C10 is charged. C10 must be set the value with enough margins. To prevent a startup failure, C10 must be set enough large value so that the CD pin voltage is less than 3.0 V during startup period. In addition, the condition when the soft start period is longest (e.g., minimum input voltage and maximum output power) should be taken into account.

## 8.15 Thermal Shutdown (TSD)

When the junction temperature of the IC reach to the Thermal Shutdown Temperature  $T_{j(TSD)} = 140 \text{ }^\circ\text{C}$  (min.), the thermal shutdown (TSD) is activated; and the IC stops switching operation in a latched state.

To release the latched state, decrease the VCC pin voltage to  $\leq V_{CC(L.OFF)}$  of 10.0 V, or decrease the VSEN pin voltage to  $\leq V_{SEN(OFF)}$  of 1.100 V, respectively.

## 9. Design Notes

### 9.1 External Components

Take care to use the proper rating and proper type of components.

#### 9.1.1 Input and Output Electrolytic Capacitors

Apply proper derating to a ripple current, a voltage, and a temperature rise. It is required to use the high ripple current and low impedance type electrolytic capacitor that is designed for switch mode power supplies.

#### 9.1.2 Resonant Transformer

The resonant power supply uses the leakage inductance of a transformer. Therefore, to reduce the effect of the eddy current and the skin effect, the wire of transformer should be used a bundle of fine litz wires.

#### 9.1.3 Current Detection Resistor, $R_{OCP}$

To reduce the effect of the high frequency switching current flowing through  $R_{OCP}$ , choose the resistor of a low internal inductance type. In addition, its allowable dissipation should be chosen suitable.

#### 9.1.4 Current Resonant Capacitor, $C_i$

Since a large resonant current flows through  $C_i$ ,  $C_i$  should be used a low loss and a high current capability capacitor such as a polypropylene film capacitor. In addition,  $C_i$  must be taken into account its frequency characteristic because a high frequency current flows.

#### 9.1.5 Gate Pin Peripheral Circuit

The VGH and VGL pins are gate drive outputs for external power MOSFETs. These peak source and sink currents are  $-540 \text{ mA}$  and  $1.50 \text{ A}$ , respectively.

To make a turn-off speed faster, connect the diode,  $D_S$ , as shown in Figure 9-1. When  $R_A$  and  $D_S$  is adjusted, the following contents should be taken into account: the power losses of power MOSFETs, gate waveforms (for a ringing reduction caused by a pattern layout, etc.), and EMI noises. To prevent the malfunctions caused by steep  $dv/dt$  at turn-off of power MOSFETs, connect  $R_{GS}$  of 10 k $\Omega$  to 100 k $\Omega$  between the Gate and Source pins of the power MOSFET with a minimal length of PCB traces. When these gate resistances are adjusted, the gate

waveforms should be checked that the dead time is ensured as shown in Figure 9-2.

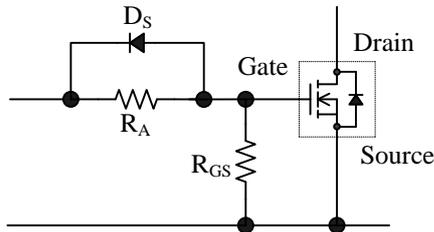


Figure 9-1. Power MOSFET Peripheral Circuit

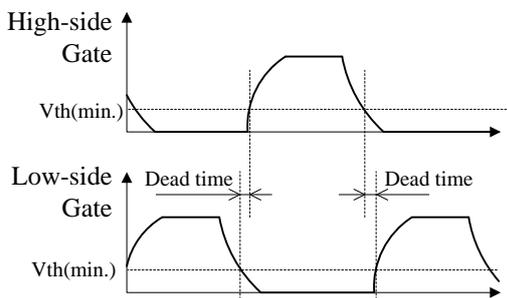


Figure 9-2. Dead Time Confirmation

## 9.2 PCB Trace Layout and Component Placement

The PCB circuit design and the component layout significantly affect a power supply operation, EMI noises, and power dissipation. Thus, to reduce the impedance of the high frequency traces on a PCB (see Figure 9-3), they should be designed as wide trace and small loop as possible. In addition, ground traces should be as wide and short as possible so that radiated EMI levels can be reduced.

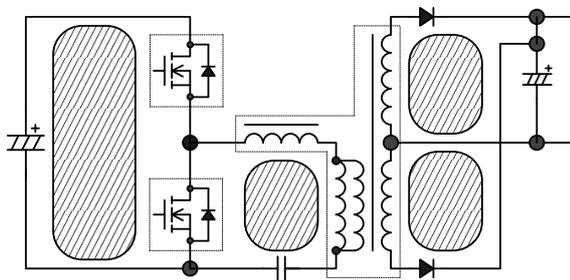


Figure 9-3. High Frequency Current Loops (Hatched Areas)

Figure 9-4 shows the circuit design example. The PCB trace design should be also taken into account as follows:

- 1) Main Circuit Trace  
The main traces that switching current flows should be designed as wide trace and small loop as possible.
- 2) Control Ground Trace  
If the large current flows through a control ground, it may cause varying electric potential of the control ground; and this may result in the malfunctions of the IC. Therefore, connect the control ground as close and short as possible to the GND pin at a single-point ground (or star ground) that is separated from the power ground.
- 3) VCC Trace  
The trace for supplying power to the IC should be as small loop as possible. If C3 and the IC are distant from each other, a film capacitor  $C_f$  (about 0.1  $\mu\text{F}$  to 1.0  $\mu\text{F}$ ) should be connected between the VCC and GND pins with a minimal length of PCB traces.
- 4) Trace of Peripheral Components for the IC Control  
These components should be placed close to the IC, and be connected to the corresponding pin of the IC with as short trace as possible.
- 5) Trace of Bootstrap Circuit Components  
These components should be connected to the IC pin with as short trace as possible. In addition, the loop for these should be as small as possible.
- 6) Secondary Side Rectifier Smoothing Circuit Trace  
The traces of the rectifier smoothing loops carry the switching current. Thus it should be designed as wide trace and small loop as possible.

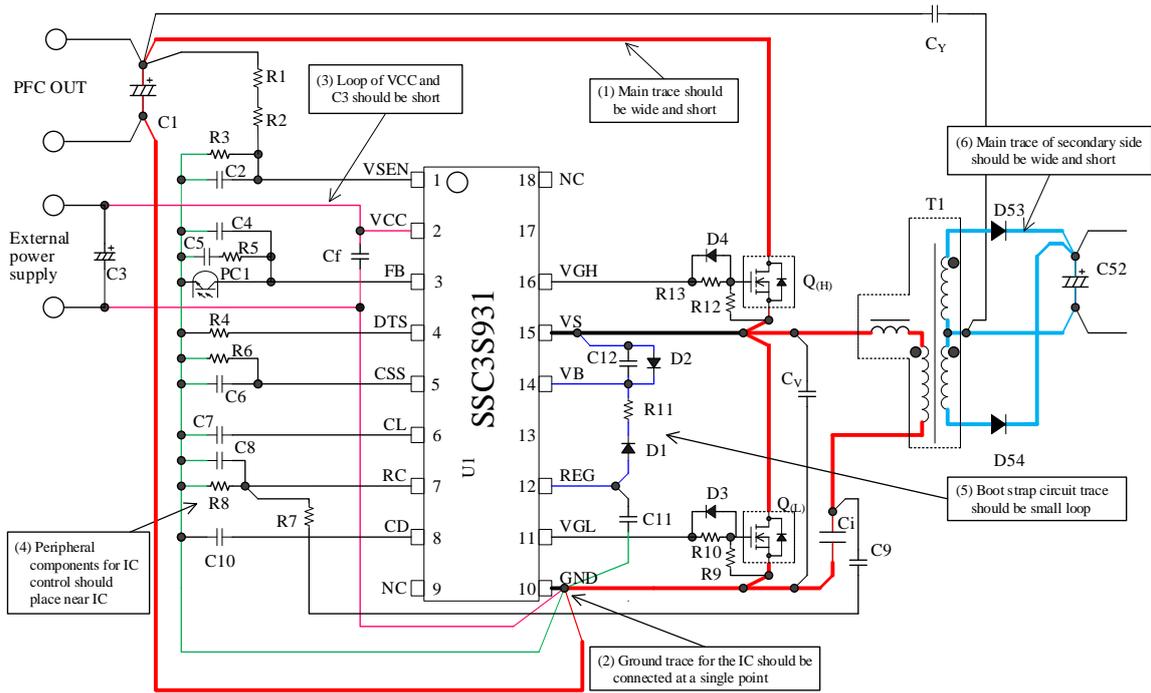


Figure 9-4. Peripheral Circuit Trace Example around the IC

### 10. Pattern Layout Example

The following show the PCB pattern layout example and the schematic of circuit using the products of SSC3S900 series. The circuit symbols correspond to these of Figure 10-1.

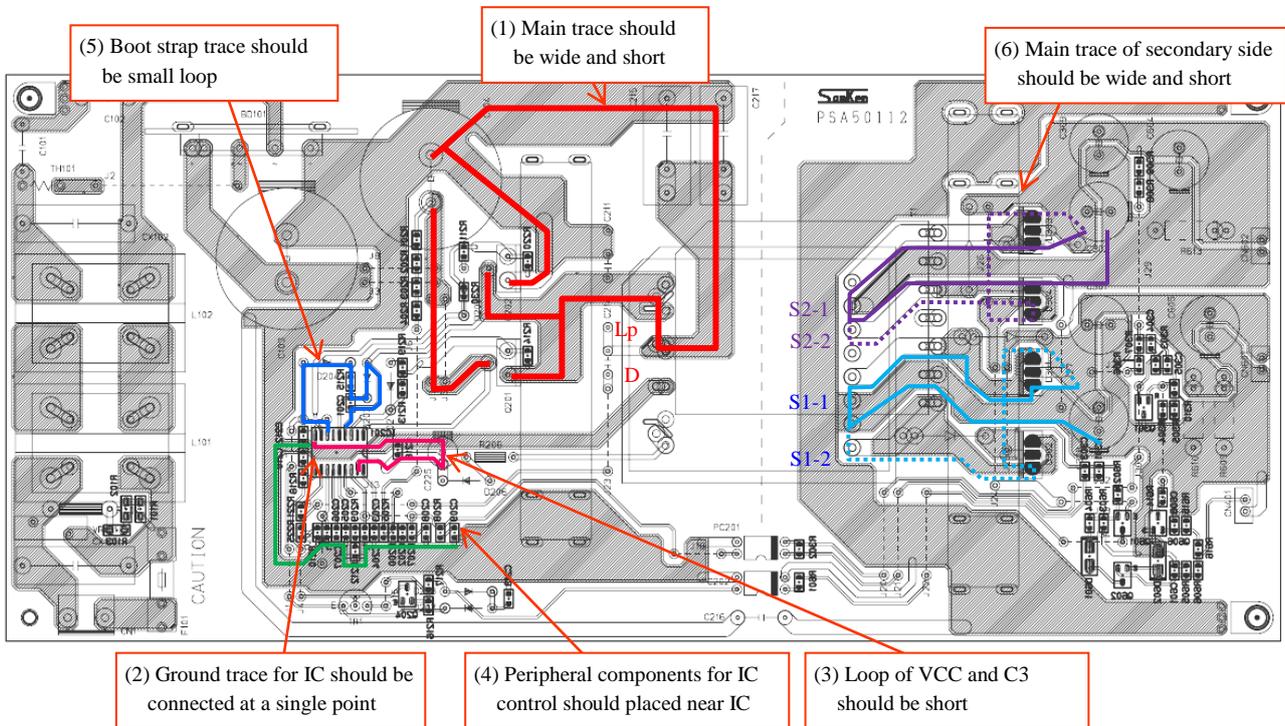
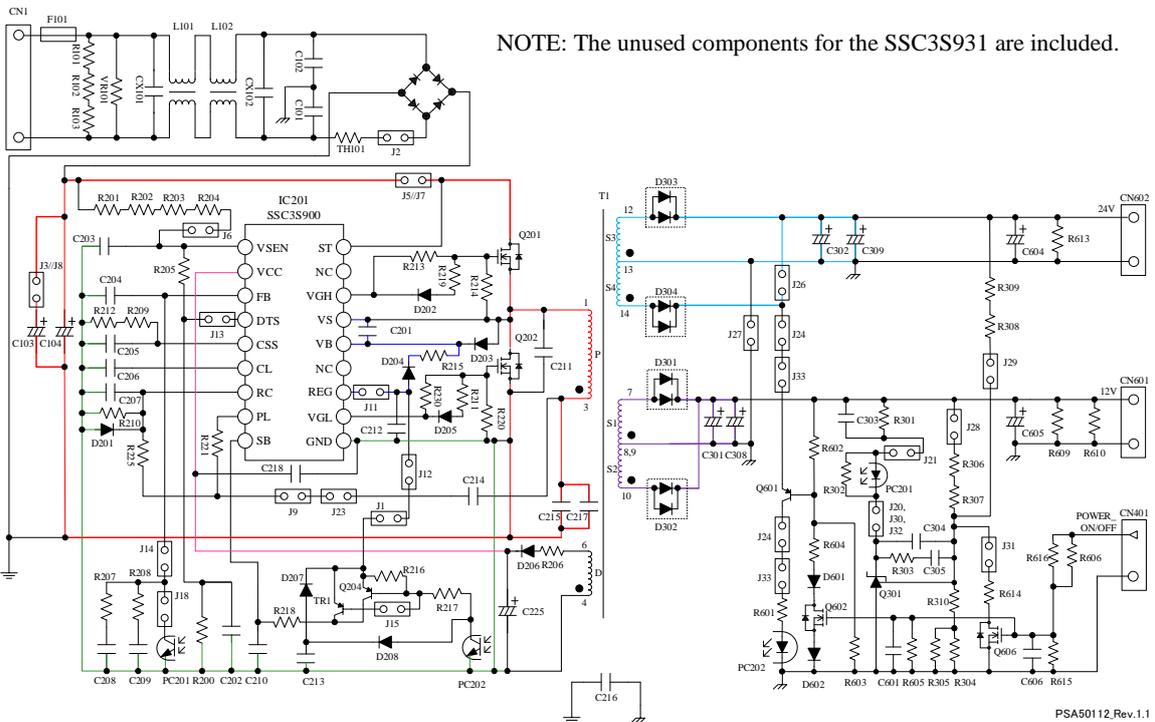


Figure 10-1. PCB circuit trace layout example



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